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<p style="text-align: center;">INFORMATION DISCLOSURE STATEMENT BY APPLICANT</p> <p style="text-align: center;">(use as many sheets as necessary)</p>				Application Number	
				Filing Date	
				First Named Inventor	Hower et al.
				Group Art Unit	
				Examiner Name	
Sheet	1	of	1	Attorney Docket No.	TI-35521

U.S. PATENT DOCUMENTS

Exam. Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
LP	AA	4,042,947		Chu et al.	08/16/1977	Entire Document
	AB	4,231,059		Hower et al.	10/28/1980	Entire Document
	AC	5,736,766		Efland et al.	04/07/1998	Entire Document
✓	AD	6,372,586	B1	Efland et al.	04/16/2002	Entire Document
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FOREIGN PATENT DOCUMENTS

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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Exam. Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
LP	CA	"Experimental and Theoretical Analysis of Energy Capability of RESURF LDMOSFETs and Its Correlation With Static Electrical Safe Operating Area (SOA)", VISHNU KHEMKA, VIJAY PARTHASARATHY, RONGHUA ZHU, AMITAVA BOSE and TOSS ROGGENBAUER, IEEE Transactions on Electron Devices, Volume 49, No. 6, June, 2002, pp. 1049-1058.	
	CB		
	CC		
	CD		
	CE		
	CF		
	CG		
	CH		

Examiner Signature	<i>LONG PHAM</i>	Date Considered	<i>7/12/04</i>
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